Theory of proxim ity e ect in norm alm etal/ $d_{x^2-y^2}$ -w ave superconductor interface in the presence of subdom inant components of the pair potentials

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Superconducting proxim ity e ect in norm alm etal (N ) /  $d_{x^2-y^2}$ -w ave superconductor (D ) junctions in the presence of attractive interelectron potentials which can induce subdom inant s-wave pair potentials both in N and D sides, is studied based on the quasiclassical G reen's function theory, where spatial dependencies of the pair potentials are determined self-consistently. In the N/D junctions with orientational angle with = 0, the s-wave component is induced in the N side by the proximity e ect only for high transparent case, where the induced s-wave components in both the N and D sides do not break the time reversal symmetry (TRS). For fully transparent case, the resulting local density of states has a very sharp zero-energy peak (ZEP), the origin of which is the sign change of the pair potentials felt by the quasiparticles between the s-wave component in the N side and  $d_{x^2-y^2}$ -wave dominant component in the D side through Andreev re ections. On the other hands, for = =4, the subdom inant s-wave component which breaks the TRS appears near the interface. Besides, for lower transparent cases, the subdom inant im aginary s-wave component is also induced near the interface in the N side. The proxim ity induced s-wave component in the N side does not enhance the magnitude of the s-wave component of the pair potential which break the TRS in the D side. The resulting LDOS at the interface has the ZEP or its splitting depending on the transparency of the junction.

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#### I. INTRODUCTION

To determ ine the pairing sym metry in unconventional superconductors is an interesting problem to understand the pairing mechanism of superconductivity. Now adays, it is widely accepted that the superconducting pair potential of high- $T_c$  cuprates has a  $d_{x^2-v^2}$ -wave symmetry in the bulk state. 1,2,3,4,5 In order to determ ine the pairing sym m etry, several phase-sensitive probes have been used<sup>1,2,4,5</sup>. Am ong them tunneling spectroscopy via Andreev bound states (ABS's), 6,7,8,9,10,11,12,13,14,15,16 help us to detect the internal phase in the pair potential. The form ation of ABS's at the Fermi energy (zero-energy), which is originated from the interference e ect in the effective pair potential of  $d_{x^2-y^2}$  -wave sym metry through the re ection at the surface/interface, plays an important role when the angle between the lobe direction of the  $d_{x^2-y^2}$ -wave pair potential and the normal to the surface/interface is nonzero.7 In fact, the existence of ABS's, which manifests itself as a distinct conductance peak at zero-bias in the tunneling spectrum (ZBCP), has been actually observed. Up to now, the consistency between theories 17,18,19,20,21,22,23,24,25,26,27,28,29,30,31,32,33,34 and experiments 35,36,37,38,39,40,41,42,43,44,45,46,47,48,49 has been checked in detail.

On the other hand, at the surface/interface of  $d_{x^2-y^2}$  wave superconductor, it is known that the time-reversal symmetry (TRS) may be broken. The reduction of the amplitude of  $d_{x^2-y^2}$ —wave pair potential near the surface/interface at low temperatures allows to in-

duce the subdom inant s-wave  $[d_{xy}$ -wave] component in the imaginary part of the pair potential, i.e., d+ is $wave^{11,18,19,20,53,54}$  [d+ id<sup>0</sup>- $wave^{55,56,57}$ ] state. The am plitude of the induced s-wave component has a maximum at = =4, which blocks the motion of quasiparticles. Then, the energy levels of ABS's shift from zero and the resulting tunneling spectra has a ZBCP splitting even in zero magnetic eld. The observation of the ZBCP splitting without magnetic elds was believed to be one of the evidence for the broken time reversal sym m etry states (BTRSS). However, actual tunneling experim ents still remain to be controversial. In fact, som e groups<sup>39,40,43,44,45,46</sup> have reported the ZBCP splitting and they ascribed the origin of the ZBCP splitting to the above BTRSS. At the same time, there are other experiments which do not show the ZBCP splitting, and in these experiments, the ZBCP survives even at low temperature. 37,38,41,42,47,48,49 Moreover, a critical current measurement of grain boundary junctions in high-T<sub>c</sub> cuprates concluded the absence of BTRSS at the interface. 58 It has been studied in detail that the ZBCP splitting in the tunneling spectra is sensitive to several factors: (i) transmission probability of the junctions, 59 (ii) roughness at the interface, 17,18,19 and (iii) e ect of impurity scattering in normal metals or superconductors. 23,25 Recent studies by Asano et al,23 revealed that the existence of the impurity scattering can induce the ZBCP splitting even without BTRSS. Taking account of these situations, one can not conclude that the observation of the ZBCP splitting by tunneling experim ents directly indicate the presence of the BTRSS

near the surface/interface.

M ore recently, it is proposed that the induced s-wave component of the pair potential by proximity e ect in norm almetals (N) may enhance the magnitude of the subdom inant s-wave component in  $d_{x^2-y^2}$ -wave superconductors (D), which forms the BTRSS based on the analysis of the tunneling experiments. 60 It is of great interest to study whether the induced s-wave component in the N side by the proxim ity e ect has the in uence on the subdominant component in the D side which forms the BTRSS. The proximity e ect in the N/D junction without the BTRSS was theoretically studied by O hashi.61 It is shown that the amplitude of the subdom inant is-wave is the largest at = -4. For = 0 with fully transparent junctions, local density of states (LDOS) at the interface has a zero energy peak (ZEP), the origin of which is not ABS but the sign change of the pair potentials between N and D sides felt by Andreev re ection of quasiparticles. It is necessary to study the interplay between the proxim ity e ect and the BTRSS by changing the orientational angle . At the same time, it is also interesting to clarify the relationship between the di erent origin of two kinds of ZEP's. One is the ZEP which originates from the form ation of ABS for \$ 0. The other is due to the proxim ity e ect expected for fully transparent junctions for = 0.61

In the present paper, we study the proxim ity e ect in N/D junctions on the basis of quasiclassical Green's function m ethods. W e assum e attractive interelectron potentials which induce subdom inant s-wave components in the N side as well as the D. The spatial dependencies of the pair potentials both in the N and D sides are determ ined self-consistently. The LDOS at the interface of the N/D junctions are studied in detail by changing and the transparency of the junction. For = -4, the magnitude of the s-wave component is induced even in the N side, while the subdom inant s-wave component which breaks TRS exists near the interface on the D side. 62 On the other hand, for = 0, s-w ave component is induced in the N side by the proximity e ect with the increase of the transparency of the junction. The induced s-wave component in the N side and that in the D side do not break the TRS. It is revealed that the proxim ity induced s-wave component in the N side does not enhance the BTRSS in the D side.

The organization of the present paper is as follows. In Sec. II, a theoretical form ulation to calculate the spatial dependence of the pair potential, and local density of states is presented. In Sec. III, results of the num erical calculations are discussed in detail. Finally, we sum marize the paper in Sec. IV.

#### II. THEORETICAL MODEL

In the present paper, we consider the N/D junction separated by an insulating interface at x=0, where the normal metal is located at x<0 and the  $d_{x^2-y^2}$ -wave

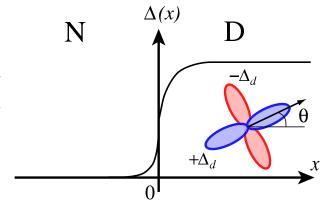


FIG. 1: Schem atic illustration of a N/D junction with a spatially varying pair potential. The m isorientation angle denotes the angle between the crystal axis of  $d_{x^2-y^2}$ -wave superconductor and the normal to the interface.

superconductor extends elsewhere (Fig. 1). For the simplicity, two dimensional system is assumed and the x axis is taken perpendicular to the interface. When quasiparticles are in the xy plane, a transmitted electron like quasiparticle and holelike quasiparticle in the D side feel different electropair potentials  $_{\rm d}$ ( +) and  $_{\rm d}$ ( ), with  $_{\rm +}=$  and  $_{\rm =}$  . Here is the azimuthal angle in the xy plane given by  $(k_{\rm x}+ik_{\rm y})=jk\;j=\;e^i$ . Besides, a cylindrical Ferm i surface is assumed and the magnitude of the Ferm imomentum and the electric mass are chosen to be equal both in the N and D sides.

In order to study the proxim ity e ect in the N/D junction, we determ ine the spatial variation of the pair potentials self-consistently. For this purpose, we make use of the quasi-classical G reen's function procedure developed by Nagai and co-workers. In the following, we brie y sum marize this scheme we employed. We introduce the generalized Eilenberger equation,  $^{63}$ 

$$i y_{Fx} j \frac{\theta}{\theta x} g \quad (;x) = \begin{cases} h & i \\ i _{m} _{3} + ^{(} & ;x) g & (;x) \\ h & i \\ + & g & (;x) i _{m} _{3} + ^{(} & ;x) ; \end{cases}$$

$$(1)$$

$$\hat{}(\ ;x) = \begin{array}{ccc} 0 & (\ ;x) \\ (\ ;x) & 0 \end{array} ; \qquad (2)$$

where  $v_{F\,x}=v_F\cos$  and ^i(i = 1;2;3) stand for the x component of the Ferm i velocity and the Paulim atrices, respectively. Here!  $_m=T(2m+1)$  (m:integer) is the M atsubara frequency.

Now, considering a sem i-in nite N/D junction geometry, the pair potential in D [N] side tend to the bulk value [zero]  $^{\rm D}$  ( ;1) [  $^{\rm N}$  ( ; 1)] at su ciently large x. In sem i-in nite lim it, we can not the quasi-classical G reen's function  $\hat{g}^{\rm l}$  ( ;x) for l(= N,D) regions given by  $^{61,64,66}$ 

$$\hat{g}^{1}$$
 ( ;x) = i  $\frac{2\hat{A}^{1}(x)}{Tr[\hat{A}^{1}(x)]}$  1 ; (3)

Following equations are satis ed for the N side,

$$A_{+}^{N}(x) = U_{+}^{N}(+;x;0)\hat{R}_{D}^{N}(0;x); \tag{4}$$

$$\hat{A}^{N}(x) = {}^{N}(x;0)\hat{R}_{D}U^{N}(x;0;x);$$
 (5)

and for the D side,

$$\hat{A}_{+}^{D}(x) = \hat{A}_{N}^{D}(x;0)\hat{A}_{N}\hat{U}_{+}^{D}(x;0;x);$$
 (6)

$$\hat{A}^{D}(\mathbf{x}) = \hat{U}^{D}(\mathbf{x}; \mathbf{x}; \mathbf{0}) \hat{R}_{N}^{D}(\mathbf{0}; \mathbf{x}); \tag{7}$$

respectively. In the above,  $\hat{R_N}$  and  $\hat{R_D}$  are matrices with re ection probability R at the interface given by 61

$$\hat{R}_{D}$$
 /  $G^{D}$  (0)  $R G_{+}^{D}$  (0)  $i(1 R)$  : (9)  $i(1 R)G_{+}^{D}$  (0) $G^{D}$  (0)  $G^{D}$  (0)  $G^{D}$  (0)  $G^{D}$  (0) : (9)

Here, we de ne G1 (x) given by

$$G^{N}(x) = i \frac{v_{n}^{N(+)}(x)}{v_{n}^{N(+)}(x)}; \quad G^{D}(x) = i \frac{v_{n}^{D(-)}(x)}{v_{n}^{D(-)}(x)}; \quad G^{D}(x) = i \frac{v$$

N ext, in order to obtain the quantities  $\tilde{U}^1$  ( ;x;x<sup>0</sup>) in Eqs. (4)-(7), we rewrite  $A^{1}$  (x)  $as^{64,66}$ 

$$\hat{A}_{+}^{N}(x) = \begin{array}{c} X_{+}^{N}(x) \\ Y_{+}^{N}(x) \end{array} \quad u_{n}^{N(+)}(_{+};x) \quad V_{n}^{N(+)}(_{+};x) \quad \hat{z};$$

$$\hat{A}^{N}(x) = \begin{array}{c} u_{n}^{N(+)}( & ;x) \\ v_{n}^{N(+)}( & ;x) \\ \end{array} \qquad X^{N}(x) Y^{N}(x) ^{2}; \quad (12)$$

$$\hat{A}_{+}^{D}(x) = \begin{array}{c} u_{n}^{D(1)}(+;x) \\ v_{n}^{D(1)}(+;x) \end{array} \qquad X_{+}^{D}(x) Y_{+}^{D}(x) \quad \hat{2}; \quad (13)$$

$$\hat{A}^{D}(x) = \begin{array}{ccc} X^{D}(x) & & & \\ Y^{D}(x) & & & \\ \end{array} \begin{array}{cccc} u_{n}^{D(1)}(& ;x) & v_{n}^{D(1)}(& ;x) & \hat{\ \ }_{2}; \end{array}$$

w ith

$$X^{N}(x) = U^{N}_{+}(x;x;0)\hat{R_{D}} \quad \begin{array}{c} U^{N}_{n}(+) & ( & ;0) \\ V^{N}_{n}(+) & ( & ;0) \end{array};$$
(15)

$$X^{N}(x) Y^{N}(x) ^{2} = u_{n}^{N(+)}(_{+};0) v_{n}^{N(+)}(_{+};0) ^{2}$$

$$\hat{R}_D \tilde{U}^N (;0;x); \qquad (16)$$

$$X_{+}^{D}(x) Y_{+}^{D}(x) ^{2} = u_{n}^{D()}( ;0) v_{n}^{D()}( ;0) ^{2}$$

$$\hat{R}_{N} \hat{U}_{+}^{D} (+;0;x);$$
 (17)

$$X^{D}(x)$$
 =  $U^{D}(x;x;0)\hat{R}_{N}$   $U_{n}^{D(x)}(x;0)$ : : (18)

Then we de ne F 1 (x) given by

$$F^{N}(x) = i \frac{X^{N}(x)}{Y^{N}(x)}; \quad F^{D}(x) = i \frac{X^{D}(x)}{Y^{D}(x)}; \quad (19)$$

Here,  $G^1$  (x) and  $F^1$  (x) in Eqs. (10) and (19), obey the following Riccatitype equations:

$$h \dot{y}_{Fx} \dot{j}_{@x}^{@} G^{1}(x) = 2!_{m} G^{1}(x) + {}^{1}(;x)G^{1}(x)^{2}$$

$${}^{1}(;x); \qquad (20)$$

$$h \dot{y}_{Fx} \dot{j}_{Qx}^{\theta} F^{1}(x) = 2!_{m} F^{1}(x) \qquad (20)$$

$$+ \qquad (21)$$

We can write the quasi-classical Green's function in a com pact form 64

$$\hat{g}^{N} \quad ( \quad ; \mathbf{x}) = \frac{\mathbf{i}}{1 \quad G^{N} (\mathbf{x}) F^{N} (\mathbf{x})} \quad \begin{array}{cccc} 1 + G^{N} (\mathbf{x}) F^{N} (\mathbf{x}) & 2 \mathbf{i} F^{N} (\mathbf{x}) \\ 2 \mathbf{i} G^{N} (\mathbf{x}) & 1 \quad G^{N} (\mathbf{x}) F^{N} (\mathbf{x}) \end{array} ; \tag{22}$$

$$\hat{g}_{++}^{D}(_{+};x) = \frac{i}{G_{+}^{D}(x)F_{+}^{D}(x)} \frac{G_{+}^{D}(x)F_{+}^{D}(x) + 1}{2iG_{+}^{D}(x)} \frac{2iF_{+}^{D}(x)}{G_{+}^{D}(x)F_{+}^{D}(x)} ;$$
(23)

with  $\hat{g}^1$  (;x) =  $\hat{g}^1_{++}$  (, ;x) . Initial conditions of these equations are as follows,

(14)

$$G^{N}(1) = 0; G^{D}(1) = \frac{D(1)}{1 + D};$$
 (24)

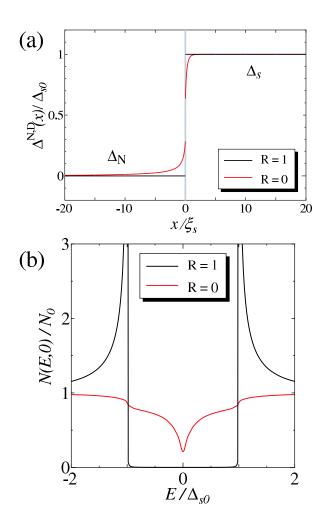


FIG. 2: (a) Spatial dependence of the pair potentials in a norm al m etal /s-wave superconductor (N/S) junction with  $T=0.02T_{\rm s}$  and  $T_{\rm N}=T_{\rm s}=10^{-3}$ . (b) The corresponding local density of states (LD O S) at the S side of the interface.

with  $^{1}$  =  $^{p}$   $\frac{1}{2}$  + j  $^{1}$  ( ;1 ) $^{2}$  . M oreover, the boundary condition of the  $G^{1}$  (0) and  $F^{1}$  (0) at the interface x = 0 are

$$F_{+}^{N} = \frac{G^{D} R G_{+}^{D} (1 R)G^{N}}{[R G^{D} G_{+}^{D}]G^{N} + (1 R)G_{+}^{D}G^{D}};$$
(25)

$$F^{N} = \frac{R G^{D} G_{+}^{D} + (1 R) G_{+}^{N}}{G_{+}^{N} [G^{D} RG_{+}^{D}] (1 R) G^{D} G_{+}^{D}}; (26)$$

$$F_{+}^{D} = \frac{RG_{+}^{N} \quad G^{N} + (1 \quad R)G^{D}}{G^{D} G_{+}^{N} \quad RG^{N} ] \quad (1 \quad R)G_{+}^{N}G^{N}}; \qquad (27)$$

$$F^{D} = \frac{G_{+}^{N} \quad R G^{N} \quad (1 \quad R)G_{+}^{D}}{[R G_{+}^{N} \quad G^{N} \ G_{+}^{D} + (1 \quad R)G^{N} G_{+}^{N}}; \qquad (28)$$

The pair potentials for both N and D sides are given

bv<sup>53,61,65,66,67</sup>

$${}^{1}(;x) = X \frac{1}{2} {}^{Z} {}^{=2} d {}^{0} V^{1}(; {}^{0})$$

$$[g^{1}(;x)]_{12}; \qquad (29)$$

where  $!_c$  is the cuto energy and  $[g^1 ( ;x)]_{12}$  m eans the 12 element of  $g^1 ( ;x)$ . Here  $V^1 ( ; )$  is the effective inter-electron potential of the Cooper pair in the 1 side. In our numerical calculations, new  $^1 ( ;x)$  and  $g^1 ( ;x)$  are obtained using Eqs.(20)-(23) and (29). We reiterate this process until the convergence is su ciently obtained.

Based on the self-consistently determined pair potentials, the LDOS can be calculated as,

$$N_1(E;x) = \frac{1}{2} = 2 d n_1(E; ;x);$$
 (30)

$$n_1(E; ;x) = Im \frac{N_0}{2} Tr \hat{g}^1 ( ;x)^3$$

$$i!_m ! E + i$$
(31)

where N  $_0$  m eans the density of states (D O S) in normal states, and is in nitesimal. In this paper, we choose the tem perature T as T=T $_d$  = 0:02, where T $_d$  is the critical tem perature of the bulk  $d_{x^2-y^2}$ -wave superconductor.

# III. RESULTS OF NUMERICAL CALCULATIONS

In this section, we show our results of num erical calculations on the spatial dependence of the self-consistently determ ined pair potentials and the corresponding LD OS. The spatial variation of the pair potentials in the N/D junction is expressed as

$$^{N}$$
 (;x) =  $_{N}$  (x); (32)

D (;x) = 
$$_{d}(x)\cos 2($$
 ) +  $_{s}(x);$  (33)

where  $_{\rm N}$  (x),  $_{\rm d}$  (x), and  $_{\rm s}$  (x) denote the am plitude of s-w ave component in the N side,  $d_{\rm x^2-y^2}$ -w ave component in the D side, and subdom inant s-w ave component in the D side, respectively. The attractive potentials V  $^1$  ( ;  $^0$ ) w ith l= N;D, are given by

$$V^{N}(;^{0}) = V_{N};$$
 (34)

$$V^{D}(;^{0}) = 2V_{d} \cos(2 \quad 2) \cos(2^{0} \quad 2) + V_{s};$$
 (35)

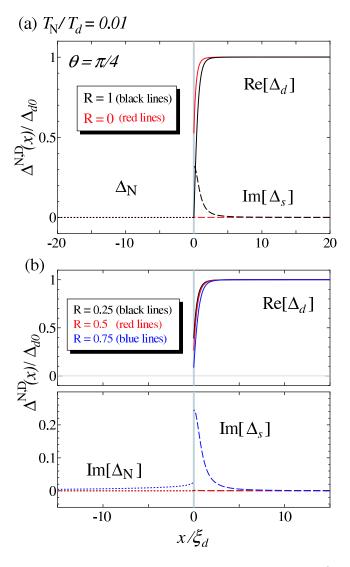


FIG. 3: Spatial dependence of the pair potentials in N/D junctions with = =4 and  $T_N=T_{\rm d}$  = 0:01. (a) R = 0 and 1, (b) R = 0:25, 0:5, and 0:75.

and

$$V_{N} = \frac{2 k_{B} T}{\ln \frac{T}{T_{N}} + X \frac{1}{m+1=2}};$$
 (36)

$$V_{d} = \frac{2 k_{B} T}{\ln \frac{T}{T_{d}} + \frac{X}{m + 1 = 2}};$$
 (37)

$$V_{s} = \frac{2 k_{B} T}{\ln \frac{T}{T_{s}} + X \frac{1}{m+1=2}};$$
 (38)

Here,  $T_N$  denotes the transition temperature of s-wave pair potential in the N side.  $T_s$  denotes the transition temperature of s-wave pair potential in the D side without  $d_{\mathbf{x}^2-\mathbf{y}^2}$ -wave attractive potential.

First, in order to understand the role of the proxim ity e ect clearly, let us check the case of norm almetal/swave superconductor (N/S) junctions. Figure 2 (a) shows the obtained spatial dependence of the pair potentials in the junctions for extremely low (R = 1) and high (R = 0)transparency cases. The x-axis of Fig. 2 is normalized by so, which is the coherence length of s-wave  $_{\rm s} = hv_{\rm F} =$ superconductor. For R = 1, the s-wave pair potential remains to be constant in S side, whereas the pair potential in the N side is zero. The spatial variation of the pair potentials is represented as a step function. The resulting LD 0 S at the interface reproduces the bulk U-shaped DOS [see Fig. 2(b)]. On the other hands, for R = 0, the pair potential N in the N side survives toward the inside. We can see that the LDOS at the interface in the presence of the proximity e ect is dierent from the bulk DOS.

#### A. N/D junction with = = 4

In this subsection, we focus on the N/D junction with (110)-oriented interface ( =-4). As the parameter of the subdom inant s-wave component, we take  $T_s=T_d=0.3$  in the following. In Figs. 3(a) and 3(b), the spatial variations of the pair potentials is shown for  $T_N=T_d=0.01$  for R=0,1, and 0.25, 0.5, 0.75, respectively. Here,  $R\in [\ _d(x)]$  and Im  $[\ _N;_s(x)]$  denote realpart of  $\ _d(x)$  and imaginary part of  $\ _N;_s(x)$ , respectively. The x-axis of Fig. 3 is normalized by the  $d_{x^2-y^2}$ -wave coherence length  $\ _d=hv_F=\ _{d0}$ , where  $\ _{d0}$  is  $d_{x^2-y^2}$ -wave pair potential in bulk states.

First, we present our results in the light of previous theories. 7,53,69 The reduction of Re[ d(x)] originates from a depairing e ect that the e ective pair potentials  $^{\mathrm{D}}$  (  $_{+}$ ;0) and  $^{\mathrm{D}}$  ( ;0) have reversed contribution to the pairing interaction for certain range of .Re[d(x)]is suppressed at the interface in the D side. At the same time, the quasiparticle forms the ABS with zero-energy at the interface. 7,69 W hen the magnitude of the rejection probability R approaches unity, the ABS becomes unstable with the introduction of the subdom inant s-wave attractive potential in the D side. And then Im [s(x)] is induced in the vicinity of the interface in the D side in low transparent cases with large magnitude of R  $^{53}$  As regards the proximity e ect in the N side, the pair potential N (x) is not induced for fully high and low transparent cases. However, the imaginary component of  $_{\rm N}$  (x) is enhanced nearly in R = 0:75 [see Fig. 3]. We can recognize that the existence of Im [s](x) near the interface of D side can allow the enhancement of the Im [  $_{\rm N}$  (x)]. This fact is more recently found by Lofwander, 62 and our results are consistent with his work.

In Figs. 4(a) and 4(b), we show the corresponding LDOS at the D side of the interface, where the same param eters of Figs. 3(a) and 3(b) are used, respectively. For R=0,  $N_D$  (E;0) is equal to  $N_0$  and has no E dependence. If we neglect the induced s-wave component in the N

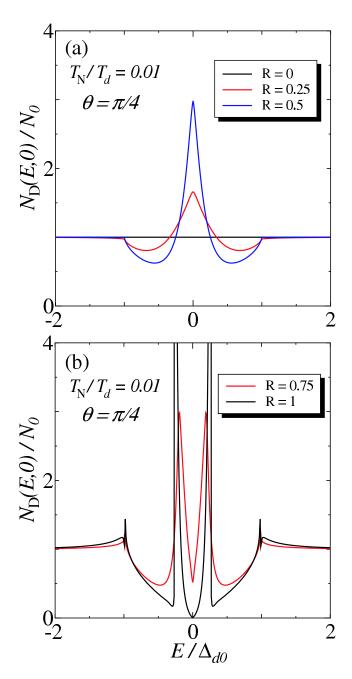


FIG. 4: The LDOS for the N/D junction with = =4 and  $T_N = T_d = 0.01$ . (a) R = 0,025, and 0.5, (b) R = 0.75 and 1.

side, the resulting LD O S has a zero-energy enhanced line shapes for small R.  $^{59}$  T his is because that the magnitude of the subdom inant s-wave component, i.e., Im [ $_{\rm S}$ (x)] is very small and the incident and rejected quasiparticles normal to the interface can feel opposite signs of the  $\rm d_{x^2-y^2}$ -wave pair potentials. However, as shown in Fig. 3 (b), not only Im [ $_{\rm N}$ (x)] but also Im [ $_{\rm S}$ (x)] remain to be non-zero due to the proximity eject. In this case, the resulting LD O S has complex line shapes. For R = 1, due to the enhancement of the magnitude of Im [ $_{\rm S}$ (x)], the LD O S has the ZEP splitting, which is consistent with

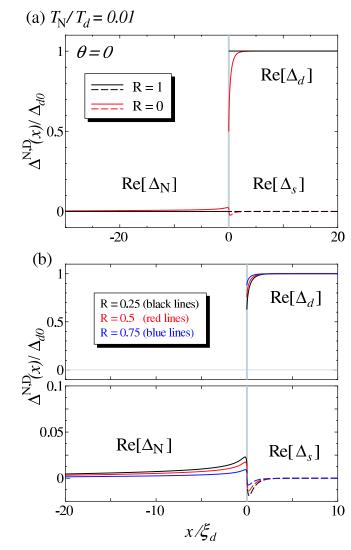
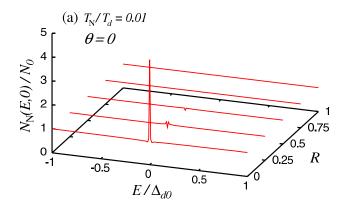


FIG. 5: Spatial dependencies of the pair potentials in N/D junctions with  $\,=\,0$  and  $T_N=T_d=\,0.01.$  (a) R = 0 and 1, (b) R = 0.25, 0.5, and 0.75.

the previous works 11,53,59.

## B. N/D junction with = 0

In this subsection, we focus on the N/D junction with = 0 and  $T_N = T_d = 0.01$ . The spatial dependencies of the pair potentials  $Re[\ _N\ (x)]$ ,  $Re[\ _d\ (x)]$ , and  $Re[\ _s\ (x)]$ , are plotted in Figs. 5 (a) and 5 (b), for R=0, 1, and 0.25, 0.5, 0.75, respectively. For the low transparent limit, R=1, [see Fig. 5 (a)], the amplitude of the pair potential is constant. This situation is similar to the case of the N/S junctions with R=1 [see Fig. 2 (a)]. With the decrease of R,  $Re[\ _d\ (x)]$  is suppressed near the interface, while  $Re[\ _s\ (x)]$  is slightly mixed in the vicinity of the interface. Since  $Im[\ _s\ (x)]=0$  is satisfied, the TRS is not broken near the (100) interface. On the other hand for the N



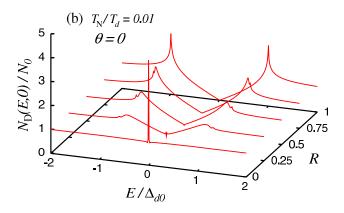


FIG. 6: (a) The LDOS at the interface by its value in the normal state for various R with = 0 and  $T_N = T_d = 0.01$ . (a) The N side, and (b) the D side.

side, we can readily see that the pair potential Re[ $_N$ (x)] is induced. This indicates that the superconducting pair potential penetrates into the N side due to the proximity e ect. With increasing the magnitude of  $T_N$ , the amplitude of Re[ $_N$ (x)] becomes larger. However, both Im[ $_S$ (x)] = 0 and Im[ $_N$ (x)] = 0 are satisfied. This situation is significantly different from the corresponding case of = 4 where the TRS is broken.

Next, let us look at the corresponding LDOS at the interface. We show that the LDOS at the interface in the N and D sides as shown in Fig. 6. For R = 1, the LDOS on the D side has a V-shaped structure sim ilar to the bulk d-wave density of states.  $^{11,53,59}$  The corresponding LDOS in the N side is constant. With the decrease of the magnitude of R, the magnitude of LDOS in the D side around zero energy is enhanced while that around

 $_{\rm d0}$  is suppressed. For R = 0.25, the LDOS has a small dip like structure both in the N and D sides. The ne structure around zero energy is due to the induced pair potential  $_{\rm N}$  (x) in the N side. The extreme case is R = 0, where normal rejection is absent. The pair potential Re[  $_{\rm N}$  (x)] induces the ZEP in the LDOS [see Fig. 6] through Andreev rejection.  $^{61}$ 

Now we concentrate on the width of this ZEP.We see that the relevance of the peak width and the in nites-

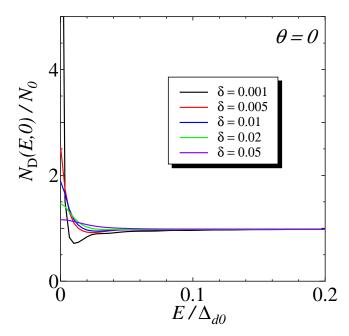
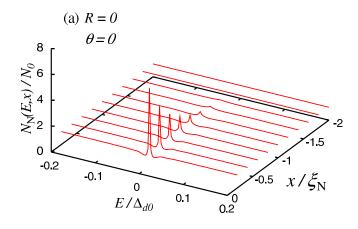


FIG. 7: The LDOS at the interface near zero energy with  $R\,=\,0$  for various  $\,$  .

im al number introduced in Eq.(31) in order to avoid divergence in the actual calculation where the inverse of can be regarded as a life time of quasiparticles. As shown in Fig. 7, the width of the ZEP becomes narrow with the decrease of the magnitude of , while the height of it increases monotonically. For ! 0 limit, the ZEP is reduced to be expressed by the —function.

In Fig. 8, we show the spatial dependence of LDOS in the N side (x < 0). For R = 0, the zero energy states formed at the interface penetrate into the N side. The width and the height of the ZEP is reduced with the increase of the magnitude of x. For R = 0:1, the LDOS has a mini gap. The width of the gap has a spatial dependence since the induced pair potential Re[  $_{\rm N}$  (x)] depends on x. The width of the mini gap is reduced with the increase of the magnitude of x.

At the end of this subsection, let us remark on the di erence on the origin of ABS's between = =4 and = 0. As mentioned in Sec. IIIA, the form ation of ABS's is originated from the opposite sign of the pair potentials between  $_{\rm d}$  (  $_{\rm f}$ ;0) and  $_{\rm d}$  (  $_{\rm f}$ ;0) felt by quasiparticles in the D side. However, in the case of = 0, there is no sign change between  $_{\rm d}$  ( $_{\rm f}$ ;0) and  $_{\rm d}$  ( $_{\rm f}$ ;0) for any . This manifestation of the ZEP in the LDOS is due to the another origin. It is due to the sign change of the pair potentials between Re[  $_{\rm N}$  (x)] and Re[  $_{\rm S}$  (x)] or that between Re[  $_{\rm N}$  (x)] and Re[  $_{\rm d}$  (x)] for j j> =4 through the Andreev rejection. Actually, by calculating the angle resolved LDOS  $n_{\rm D}$  (E; ;x) in Eq.(31),  $n_{\rm D}$  (E; ;x) has the ZEP for = =3 while it does not for = =6 as shown in Fig.9.



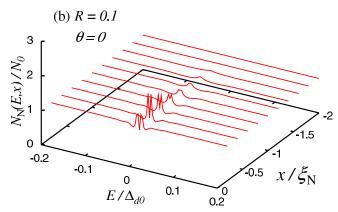


FIG. 8: The LDOS at x < 0 w ith  $\,=\,$  0. (a) R = 0 and (b) R = 0:1 for various x. Here  $_{\rm N}$  =  $v_{\rm F}$  =2 T is the coherence length in the N side w ith T = 0:02T\_d.

## C. N/D junction with = =6

In this subsection, we concentrate on the case with interm ediate angle , e.g., = =6. The spatial dependencies of the pair potentials become very complicated as shown in Fig. 10, where we choose  $T_N = T_d = 0.01$  for various R. For R = 0, the amplitude of Re[N(x)] is induced toward the inside of N. This situation is similar to the case of = 0 by the proxim ity e ect. W ith the increase of R, the amplitude of Re[d(x)] is signicantly suppressed at the interface, due to the destructive interference originating from the sign changing nature of  $d_{x^2}$  wave pair potential. The amplitude of Re[ N (x)] is suppressed due to the reduction of the proximity e ect. On the other hand, am plitudes of Im [d(x)], Re[d(x)], and Im [s(x)] are enhanced. As regards the subdom inant components, the amplitude of Im [s(x)] for lower transparent cases R = 0.75 and R = 1, is one order larger than those of Im [a(x)], and Re[s(x)] [see Fig. 10(b)]. In particular, for R = 0.75, the situation that the amplitude of  $\operatorname{Im} [N(x)]$  is induced near the interface of N side is sim ilar to the case of = -4. Subdom inant com ponents which break TRS is induced also by the proxim ity e ect and depends on the transparencies of the junction.

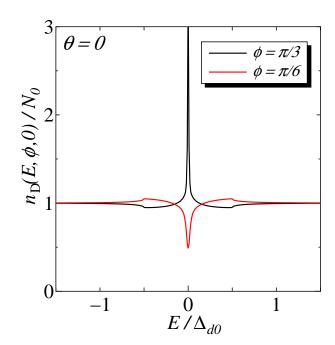


FIG. 9: Angle resolved LDOS at the interface for  $\ = \ 0$  and  $R = \ 0$ .

The corresponding LDOS for = =6 are plotted in Figs. 11(a) and 11(b). Here, we choose  $T_N = T_d = 0.01$ , which is the same parameters used in Fig. 10. The resulting line shapes of LDOS are complex re ecting on the complicated spatial dependence of the pair potentials. For R = 0, we can see that the zero energy states are formed at the interface and the resulting LDOS has a ZEP due to the proxim ity e ect. This ZEP, the origin of which is similar to the case of = 0 [see Fig. 6(b)], arises from the sign change of the pair potentials between Re[N(x)] and  $Re[d_{s}(x)]$  through Andreev rejections due to proximity e ect. With the increase of R, the LDOS has a rather broad ZEP. due to the form ation of ABS's. This ZEP for intermediate value of Roriginates from the formation of ABS's peculiar to unconventional superconductors<sup>8,12</sup>, i.e. with sign change of the pair potentials between  $_{d}(+;0)$  and  $_{d}(-;0)$ . With the further increase of R , (see the curve with R = 0.75), since the imaginary components of both  $_N$  (x) and  $_s$  (x) are induced in the vicinity of the interface, the line shape of the LDOS has a complicated structure re ecting on the complex spatial dependence of pair potentials. For R = 1, the LDOS has the ZEP splitting due to the existence of subdom inant s-wave component which breaks TRS in the D side, i.e., Im [s(x)]. As a results, in the N/D junctions with = =6, we can conclude that the line shapes of the LDOS around zero energy change from (I) the ZEP due to proxim ity e ect, (II) the ZEP due to the ABS, and (III) the ZEP splitting due to the form ation of the BTRSS, with the increase of the magnitude of R.

Finally, we look at the angle resolved LDOS  $n_D$  (E; ;x) in order to understand the basic features of

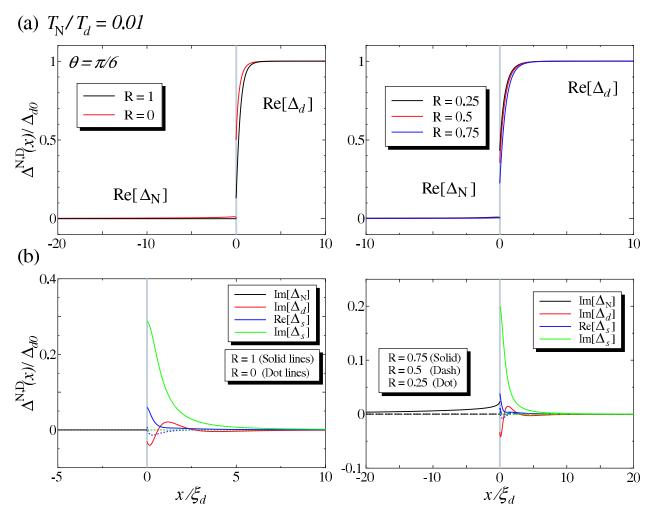


FIG .10: Spatial dependencies of the pair potentials for the N/D junctions with = = 6 and  $T_N = T_d = 0.01$ . In (a), Re[N(x)], Re[N(x)], Re[N(x)], and in (b), Im[N(x)], Im[N(x)], Re[N(x)], Re[N(x)], Im[N(x)], Im[N(x

the line shapes of N  $_{\rm D}$  (E;0). In Figs. 12 and 13, the angle resolved LDOS  $n_D$  (E; ;x) at the interface is plotted for = =6 and R = 0:75. In order to understand the role of the induced pair potential in N region, we intentionally neglect the pair potential N (x) in the N side in the actual calculation of LDOS as shown in the upper panel of Fig. 12 and Fig. 13. We also consider the case, where induced s-wave component  $_{s}$  (x) is neglected in the calculation of LDOS. First we concentrate on the upper panels where N (x) is absent. If only the pure  $d_{x^2}$  v<sup>2</sup> -w ave component exists in the D side, the quasiparticles from the ABS's at zero energy. For = since  $_{d}(_{+};0)$   $_{d}(_{+};0)<0$  is satis ed,  $n_{D}$  (E; ;0) has the ZEP [see Figs. 12 (a) and 12 (b)]. In the presence of the subdom inant s-wave component which breaks TRS in the D side, the resulting  $n_D$  (E; ;0) is modified. In this case, the line shape of  $n_D$  (E; ;0) is not asymmetric around E = 0, i.e., where  $n_D$  (E; ;0)  $\notin$   $n_D$  (E; ;0), due to the form ation of the BTRSS. Therefore, the peak position of n<sub>D</sub> (E; ;0) is shifted from zero energy. On the other hands, for = =20, as  $_{d}(_{+};0)$   $_{d}(_{;0}) > 0$ 

is satis ed,  $n_D$  (E;;0) has gap structures [see Figs. 13 (a) and 13 (b)]. These results are consistent with those by M atsum oto and Shiba. Next, we look at lower panels of Figs. 12 and 13. Since induced Im [ $_N$ (x)] breaks time reversal symmetry, the resulting line shape of LDOS is no more symmetric around E = 0, even for  $_S$ (x) = 0. As shown in the lower panels, the presence of  $_N$ (x) forms a minigap around zero energy E = 0.

In Fig. 14, the LDOS  $n_D$  (E;;0) is plotted for R=0, where the Andreev rejection only exists. In this case, the line shape of the LDOS can be understood only by taking into account the pair potentials  $_N$  (x) and  $_d$  (x). For = =3 and = =20, the LDOS has no ZEP since  $_N$  (+;0)  $_d$  (+;0) > 0 is satisfied. The resulting  $n_D$  (E;;0) has a gap structure [see Figs. 14(a) and 14(b)]. If the quasiparticle's scattering feel different sign of the pair potentials between the N and D sides, we can expect that the  $n_D$  (E;;0) has the ZEP even for R=0. For = =3, since  $_N$  (+;0)  $_d$  (+;0) < 0 is satisfied, then the  $n_D$  (E;;0) has the ZEP [see Fig. 14(b)]. These situations are similar to those studied in Sec. IIIB.

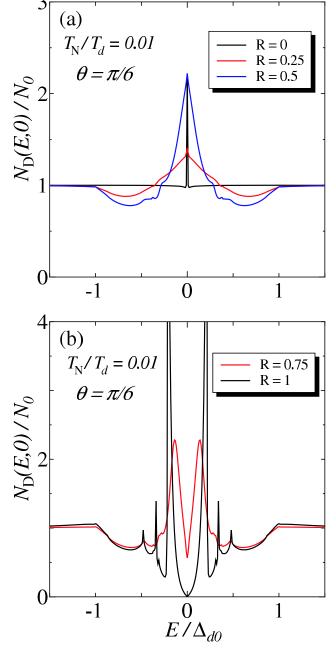


FIG. 11: The LDOS for the N/D junctions with = = 6 and  $T_N = T_d = 0.01$ . (a) R = 0,0.25, and 0.5, (b) R = 0.75 and 1.

# IV. CONCLUSIONS

In this paper, we have studied quasiparticle properties in the N/D junctions, in the presence of the proximity e ect as well as the BTRSS in the D side. We assume the attractive interelectron potentials which induces subdom inants-wave components both in the N and D sides. The spatial dependencies of the pair potentials in the N/D junctions are determined self-consistently. The LDOS at the interface of the N/D junctions are

studied in detail by changing orientational angle and the transparency of the junction. Our main results are sum marized as follows.

i) For (110) oriented junction with  $\,=\,$  =4, the predom inant  $d_{x^2-y^2}$ —wave component in the D side is reduced at the interface. The subdom inant s-wave component which breaks TRS appears near the (110) interface in low transparent cases. In the N side, subdominant in aginary s-wave component is induced near the interface  $^{62}$ . The resulting LDOS at the interface in the N side has the ZEP or its splitting depending on the transparency of the junction. These results are consistent with previous theoretical works.  $^{11,53,54,59,62}$ 

ii) For (100) oriented junction, the subdom inant swave component becomes real number and does not break TRS $^{62}$ . With the increase of the transparency of the junction, the magnitude of the swave component in the N side is enhanced by the proximity elect. For fully transparent case, the LDOS has very sharp ZEP due to the form ation of zero energy states. This ZEP originates from the fact that quasiparticles feel dierent sign of the pair potentials between the N and D sides through Andreev rejection.

iii) For = =6, the spatial dependencies of the pair potentials become very complicated. The resulting LDOS has a wide variety. For high barrier limit, the LDOS has the ZEP splitting.

In the light of our results, although the penetration of the pair potential into the N side by the proximity e ect is expected for (100) oriented junctions, the subdom inant s-wave components both in the N and D sides are real numbers. Thus, the BTRSS is not formed in the (100) junctions. The present results are inconsistent with previous prediction based on tunneling experiment on high- $T_{\rm c}$  cuprates by K ohen et al. In order to understand their experimental results, we must seek for other possibilities.

In the present paper, we study proxim ity e ect in N/D junctions in the ballistic lim it. In the actual junctions, we can not neglect im purity scattering e ect. To reply this issue, two of the present author present theoretical works of charge transport in N/D junctions in the presence of the ABS where the N region is a di usive m etal.  $^{26,70}$  It is an interesting problem to extend the present theory in the di usive regime based on the K eldysh G reen's function form alism  $^{70}$  A lthough there are many works about ABS's in unconventional superconductor junctions up to now,  $^{71,72,73,74,75,76,77,78,79,80,81,82,83,84,85,86,87,88,89,90,91,92,93,94,95,96,97}$ 

proxim ity e ects both in the presence of induced pair potential in the N region and the ABS's are not fully studied. Recent study by Lofwander is remarkable where the proxim ity e ect is studied in the presence of both in purity scattering and induced subdom inant component of the pair potentials. Based on his detailed calculation, for (100) junction, a real combination of the proxim ity e ect is always found. For (110) orientation, the s-wave component induced by the proxim ity e ect in the N side breaks TRS. These results are consistent

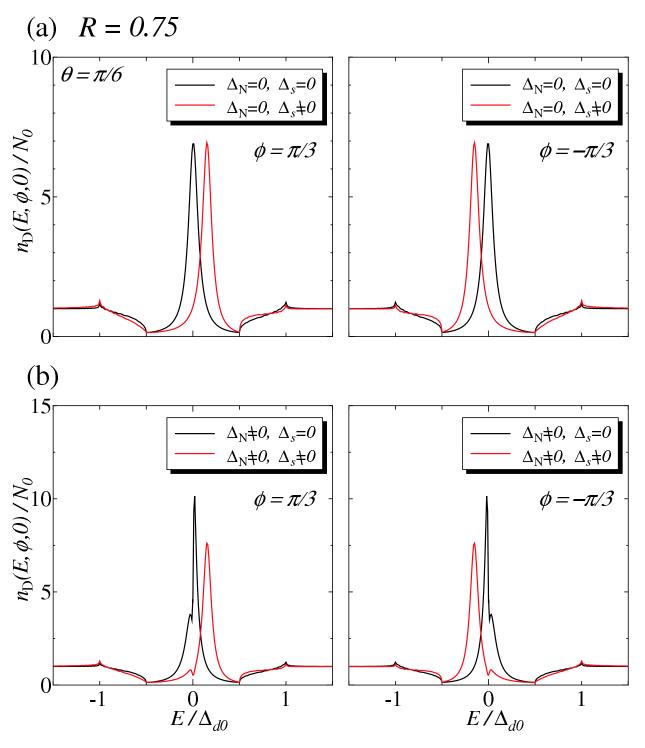


FIG. 12: The angle resolved LDOS  $n_D$  (E; ;x) at the interface with = =6 and R = 0.75. (a): LDOS without subdom inant s-wave pair potential in the N side. (b): LDOS in the presence of subdom inant s-wave pair potential in the N side. = =3 for the left panel and = =3 for the right panel.

with the present results.

the present theory towards these directions.

As a future problem, to clarify the charge transport property in Josephson junctions both in the presence of ABS  $^{104,105,106,107,108,109,110,111,112,113,114,115,116,117,118,119,120,121,122}$  and proxim ity e ect is interesting. We want to extend

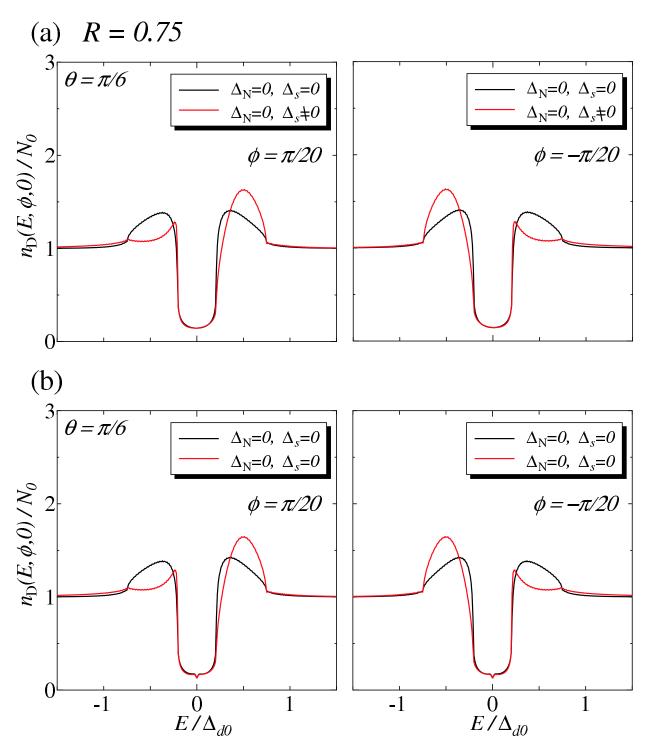


FIG. 13: The angle resolved LDOS  $n_D$  (E; ;x) at the interface with = = =6 and R = 0:75. (a): LDOS without subdom inant s-wave pair potential in the N side. (b): LDOS in the presence of subdom inant s-wave pair potential in the N side. = =20 for the left panel and = =20 for the right panel.

#### A cknow ledgm ents

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We would like to sincerely thank Dr. T. Lofwander for critical reading of the manuscript and valuable discussions. The computations have been performed at the

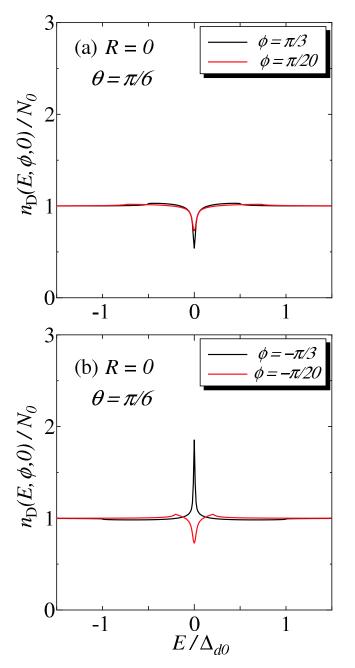


FIG. 14: The angle resolved LDOS  $n_D$  (E; ;x) at the interface with = =6 and R = 0. (a) = =3, =20, and (b) = =3, =20.

APPENDIX A:BOGOLIUBOV-DE GENNES EQUATION AND QUASI-CLASSICAL APPROXIMATION

Our theoretical formalism is started from the Bogoliubov-de Gennes (BdG) equation for unconven-

tional spin-singlet superconductors,

$$E_n \alpha_n (r) = H_0 \alpha_n (r) + \frac{1}{2} dr^0 (r; r^0) \nabla_n (r^0);$$
 (A1)

$$E_n v_n (r) = H_0 v_n (r) + dr^0 (r; r^0) v_n (r^0); (A2)$$

$$H_0 = \frac{h^2}{2m} r^2$$
;

where is the chem ical potential, while  $\alpha_n$  (r) and  $v_n$  (r) denote the electron like and holelike components of the wave function

$$\begin{array}{lll} \tilde{v}_{n} \; (r) = & \begin{array}{lll} w_{n} \; (r) \\ & v_{n} \; (r) \end{array} ; \\ & \begin{array}{lll} u_{n} \; (\hat{k}; r) \\ & v_{n} \; (\hat{k}; r) \end{array} \; e^{ik_{F} \; \hat{k}} \; \stackrel{r}{=} & _{n} \; (\hat{k}; r) e^{ik_{F} \; \hat{k}} \; \stackrel{r}{:} \; (A \; 3) \end{array}$$

Here the quantities  $\hat{k}$  and r stand for the unit vector of the wave number of the Cooper pair which is xed on the Ferm i surface ( $\hat{k}=k_F=j_{k_F}$ ), and the position of the center of mass of Cooper pair, respectively. A fter applying the quasi-classical approximation, the BdG equation is reduced to the Andreev equation  $^{7,67,68}$ ,

is reduced to the Andreev equation 
$$^{7,67,68}$$
,

$$E_{n-n}(\hat{k};r) = \text{ihv}_F \hat{k} + (\hat{k};r) + (\hat{k};r) + (\hat{k};r);$$
(A 4)

$$\hat{(\hat{k};r)} = \begin{pmatrix} 0 & (\hat{k};r) \\ (\hat{k};r) & 0 \end{pmatrix} : (A5)$$

The wave function  $_n(\hat{k};r)$  is obtained by neglecting the rapidly oscillating plane-wave part following the quasi-classical approximaation  $^{67,68}$ . The  $\hat{k}$  dependence of  $(\hat{k};r)$  represents the symmetry of the pair potential.

In the present study, we consider the case where a secularly rejection or interface runs along the y direction. Then, the pair potential depends only on x since the system is hom ogeneous along the y direction. The wave function  $_n$  (k̂;r) can be written in the following directional notation:  $_n^{53,65}$ 

Here represents the sign of the x component of the Ferm i wave number  $k_{F\,x}$  and () = . We de ne a Green's function G (;x;x $^0$ ) and a quasi-classical Green's function q (;x)

G 
$$(;x;x^{0}) = \frac{X}{n} \frac{\binom{n}{n} (;x) \binom{n}{n} (;x^{0})^{y}}{i!_{m} E_{n}};$$
(A 7)

g (;x) 
$$i(^3) = 2h j_{V_F x} j_3^3 G$$
 (;x 0;x):
(A8)

where  $^{3}$  is the Paulim atrix in the directional space  $^{65}$ .

APPENDIX B:EVOLUTION OPERATOR U<sup>1</sup> ( ;x;x<sup>0</sup>)

The quasi-classical Green's function can be written by the following evolution operator  $U(x;x^0)$  as

where U  $(;x;x^0)$  satisfies the Andreev equation

$$ih j_{v_{Fx}} j_{ex}^{0} U \quad (;x;x^{0})$$

$$= i!_{m} ^{3} + (;x) U \quad (;x;x^{0}); \quad (B2)$$

with U ( ;x;x) = 1.

Hence, the evolution operators in the 1 side can be divided into a growing part and a decaying part

$$U^{1}(\ ;x;x^{0}) = \ ^{1(+)}(\ ;x;x^{0})e^{\ ^{1}(x-x^{0})} + \ ^{1(-)}(\ ;x;x^{0})e^{\ ^{1}(x-x^{0})}; \quad (B3)$$

$$^{1(+)}(\ ;x;x^{0}) = \ \frac{1}{W^{1}} \ ^{1(+)}_{n}(\ ;x)^{T} \ ^{1(-)}_{n}(\ ;x^{0})^{2};$$

$$^{1(-)}(\ ;x;x^{0}) = \frac{1}{W^{1}} \ ^{1(-)}_{n}(\ ;x)^{T} \ ^{1(+)}_{n}(\ ;x^{0})^{2}; \quad (B4)$$

w here

$$\begin{array}{lll}
1 &=& \frac{1}{j y_{F \times j}}; & 1 &=& \frac{q}{\lfloor \frac{2}{n} + j^{-1}(\cdot; 1) j^{2}}; & (B5) \\
W^{1} &=& \frac{1}{n} \frac{1(+)}{n} (\cdot; x) \hat{2} \frac{1(-)}{n} (\cdot; x) \\
&=& \frac{1}{n} \frac{1(-)}{n} (\cdot; x) \hat{2} \frac{1(+)}{n} (\cdot; x) \\
&=& \text{const:} & (B6)
\end{array}$$

In the above,  $\begin{bmatrix} T & 1 & 1 \\ n & 1 \end{bmatrix}$  ( ;x) denotes the transposition of  $\begin{bmatrix} 1 & 1 \\ n & 1 \end{bmatrix}$  ( ;x). In the actual numerical calculations, we use  $\begin{bmatrix} T^1 & 1 \\ 1 & 1 \end{bmatrix}$  ( ; x;0) and  $\begin{bmatrix} T^1 & 1 \\ 1 & 1 \end{bmatrix}$  ( ; 0;x) given by

$$U_{+}^{N}(_{+};x;0) = U_{+}^{N}(_{+};x;0)e_{+}^{N}x;$$
 (B7)

$$U_{+}^{D}(+;0;x) = U_{+}^{D}(+;0;x)e^{-\frac{D}{+}x}$$
: (B8)

# APPEND IX C:FOR AVOID ING DIVERGENCE IN OUR CALCULATION

In particular, if  $^{N}$  (  $_{+}$ ; 1 ) [  $^{D}$  (  $_{;}$ 1 )]= 0, we can nd  $G_{+}^{N}$  [ $G^{D}$ ]! 1. In this case, instead of Eq. (20), we solve the following equation as

$$h j_{V_{F \times}} j_{e \times} \frac{0}{e^{e} \times} \frac{1}{G^{1}(x)} = 2!_{m} \frac{1}{G^{1}(x)} + {}^{1}(;x) \frac{1}{G^{1}(x)} {}^{2} + {}^{1}(;x) \frac{1}{G^{1}(x)}$$

under initial condition,

$$\frac{1}{G^{1}(x)} = \frac{1(; 1)}{!_{m} + 1}: (C2)$$

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